

09/18/01

ISSUE CLASSIFICATION	
Class	Subclass

N

PATENT NUMBER

U.S. **UTILITY** Patent Application

O.I.P.E.

PATENT DATE

SCANNED

9.4

APPLICATION NO. 09/955641	CONT/PRIOR	CLASS 365	SUBCLASS 104	ART UNIT 2818 2824	EXAMINER HIEN NGUYEN
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APPLICANTS

Jack Pano

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FILE

Semiconductor memory cell and memory array using a breakdown phenomena in an ultra-thin dielectric

PTO-2040
12/89

ISSUING CLASSIFICATION

[illegible]

<input type="checkbox"/> TERMINAL DISCLAIMER	DRAWINGS			CLAIMS ALLOWED	
	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G.
<input type="checkbox"/> The term of this patent subsequent to _____ (date) has been disclaimed.	_____ (Assistant Examiner) _____ (Date)			NOTICE OF ALLOWANCE MAILED	
<input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S. Patent. No. _____ _____ _____	_____ _____ (Primary Examiner) _____ (Date)			ISSUE FEE	
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